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STGP7NC60H



N-channel PowerMESH™ 600 V, 14 A very fast IGBT

Datasheet - obsolete product

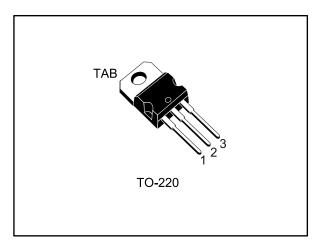
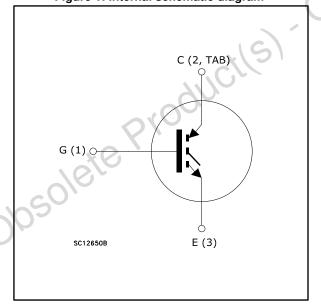


Figure 1: Internal schematic diagram



Features

Order code	V _{CES}	V _{CE(sat)} max @ 25°C	Ic @ 100°C	
STGP7NC60H	600 V	< 2.5 V	14 A	

- Low on-voltage drop (V_{CE(sat)})
- High frequency operation up to 70 kHz

Applications

- High frequency inverters
- SMPS and PFC in both hard switch and resonant topologies
- Motor drivers

Description

This device is a very fast IGBT developed using advanced PowerMESH™ technology. This process guarantees an excellent trade-off between switching performance and low on-state behavior. This device is well-suited for resonant or soft-switching applications.

Table 1: Device summary

Order code	Marking	Package	Packing
STGP7NC60H	GP7NC60H	TO-220	Tube

Contents STGP7NC60H

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STGP7NC60H Electrical ratings

1 **Electrical ratings**

Table 2: Absolute maximum ratings

Parameter	Value	Unit				
Collector-emitter voltage (V _{GE} = 0)	600	V				
Gate-emitter voltage	±20	V				
Continuous collector current at T _C = 25 °C ⁽¹⁾	25	Α				
Continuous collector current at T _C = 100 °C ⁽¹⁾	14	Α				
Collector current (pulsed)	50	Α				
Continuous forward current at T _C = 25 °C	80	W				
Storage temperature range Operating junction temperature range - 55 to 150						
				Notes: (1) Calculated according to the iterative formula: $I_C(T_C) = \frac{T_{JMAX} - T_C}{R_{THJ-C} \times V_{CESAT(MAX)}(T_{J(max)} \times I_C(T_C))}$ (2) Pulse widht limited by maximum junction temperature.		
	Collector-emitter voltage ($V_{GE} = 0$) Gate-emitter voltage Continuous collector current at $T_C = 25$ °C (†) Continuous collector current at $T_C = 100$ °C (†) Collector current (pulsed) Continuous forward current at $T_C = 25$ °C Storage temperature range Operating junction temperature range according to the iterative formula: $T_{JMAX} - T_C$ $T_{J-C} \times V_{CESAT(MAX)}(T_{J(max)} \times I_C(T_C))$	Collector-emitter voltage (V _{GE} = 0) 600 Gate-emitter voltage ± 20 Continuous collector current at T _C = 25 °C (1) 25 Continuous collector current at T _C = 100 °C (1) 14 Collector current (pulsed) 50 Continuous forward current at T _C = 25 °C 80 Storage temperature range -55 to 150 Operating junction temperature range -55 to 150				

Notes:

$$I_C(T_C) = \frac{T_{JMAX} - T_C}{R_{THJ-C} \times V_{CESAT(MAX)}(T_{J(max)} \times I_C(T_C))}$$

Table 3: Thermal data

	Symbol	Parameter	Value	Unit
	R _{thj-case}	Thermal resistance junction-case max	1.56	°C/W
	R _{thj-amb}	Thermal resistance junction-ambient max	62.5	°C/W
Obsoli	R _{thj-case} Thermal resistance junction-case max R _{thj-amb} Thermal resistance junction-ambient max			

 $^{^{(2)}}$ Pulse widht limited by maximum junction temperature.

Electrical characteristics STGP7NC60H

2 Electrical characteristics

T_C = 25 °C unless otherwise specified

Table 4: Static characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
$V_{(BR)CES}$	Collector-emitter breakdown voltage	$V_{GE} = 0 \text{ V}, I_C = 1 \text{ mA}$	600			٧
		$V_{GE} = 15 \text{ V}, I_{C} = 7 \text{ A}$		1.85	2.5	
VCE(cat)	Collector-emitter saturation voltage	V _{GE} = 15 V, I _C = 7 A, T _J = 125 °C		1.7		V
$V_{\text{GE(th)}}$	Gate threshold voltage	$V_{CE} = V_{GE}$, $I_C = 250 \mu A$	3.75		5.75	V
		V _{GE} = 0 V, V _{CE} = 600 V			10	μΑ
Ices	Collector cut-off current	$V_{GE} = 0 \text{ V}, V_{CE} = 600 \text{ V},$ $T_{C}=125 \text{ °C} \text{ (1)}$	1		1	mA
I _{GES}	Gate-emitter leakage current	V _{CE} = 0 V, V _{GE} = ±20 V	0		±100	nA

Notes:

Table 5: Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
gfs ⁽¹⁾	Forward transconductance	V _{CE} = 15 V, I _C = 7 A		4.30		Ø
Cies	Input capacitance	,		720		pF
Coes	Output capacitance	V _{CE} = 25 V, f = 1 MHz, V _{GE} = 0 V		81		рF
Cres	Reverse transfer capacitance			17		рF
Qg	Total gate charge	V _{CE} = 390 V, I _C = 7 A, V _{GE} = 15 V		35	48	
Qge	Gate-emitter charge	(see Figure 18: "Gate charge test		7		nC
Qgc	Gate-collector charge	circuit")		16		
Icl	Turn-off SOA minimum current	$\begin{aligned} V_{\text{clamp}} &= 480 \text{ V}, T_j = 150 ^{\circ}\text{C}, \\ R_G &= 10 \Omega, V_{GE} = 15 \text{V} \end{aligned}$	50			Α

Notes:

 $[\]ensuremath{^{(1)}}\mbox{Defined}$ by design, not subject to production test.

⁽¹⁾Pulsed: Pulse duration= 300 μs, duty cycle 1.5%

Table 6: IGBT switching characteristics (inductive load)

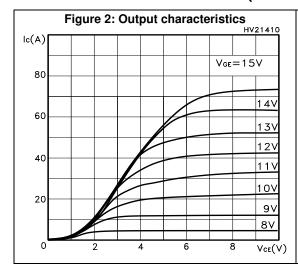
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on delay time		-	18.5		ns
$t_{r(on)}$	Turn-on rise time		1	8.5		ns
di/dt _(on)	Turn-on current slope	$V_{CC} = 390 \text{ V}, I_{C} = 7 \text{ A},$	-	1060		A/μs
tr(off)	Turn-off rise time	$V_{GE} = 15 \text{ V}, R_G = 10 \Omega$	-	27		ns
t _{d(off)}	Turn-off delay time	(see Figure 16: "Ic vs frequency" and Figure 17:	-	72		ns
tf	Fall time	"Test circuit for inductive load	-	60		ns
E _{on} ⁽¹⁾	Turn-on switching energy	switching")	-	95	125	μJ
E _{off} ⁽²⁾	Turn-off switching energy			115	150	μJ
Ets	Total switching energy			210	275	μJ
t _{d(on)}	Turn-on delay time		1	18.5	S	ns
$t_{r(on)}$	Turn-on rise time		-	7		ns
di/dt _(on)	Turn-on current slope		- 2	1000		A/μs
tr(off)	Turn-off rise time	$V_{CE} = 390 \text{ V}, I_{C} = 7 \text{ A}, \\ V_{GE} = 15 \text{ V}, R_{G} = 10 \Omega$	6	56		ns
$t_{d(off)}$	Turn-off delay time	T _J = 125 °C)'	116		ns
tf	Fall time	(see Figure 17: "Test circuit for inductive load switching")	-	105		ns
E _{on} (1)	Turn-on switching energy	Tor madelive load switching)	1	140		μJ
E _{off} (2)	Turn-off switching energy		ı	215		μJ
Ets	Total switching energy	202	-	355		μJ

Notes:

⁽¹⁾Including the reverse recovery of the diode.

⁽²⁾Including the tail of the collector current.

2.2 Electrical characteristics (curves)



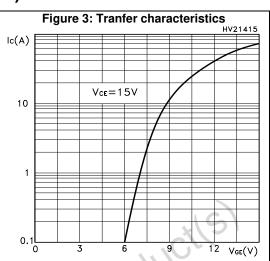


Figure 4: Trasconductance

HV21420

TJ=-50°C

VCE=15V

125°C

125°C

4

3

2

10

3

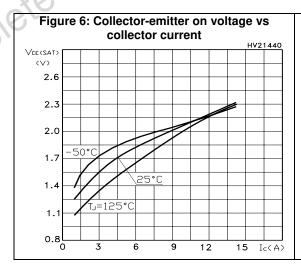
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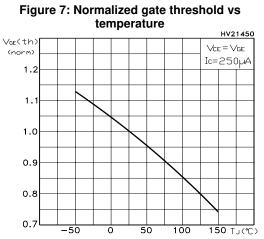
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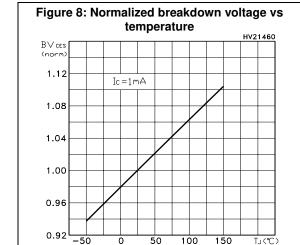
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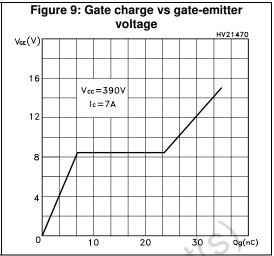
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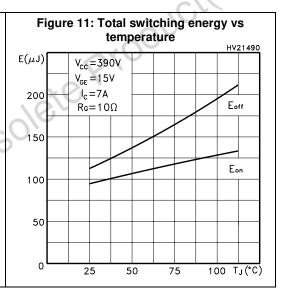
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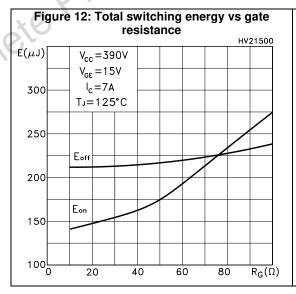


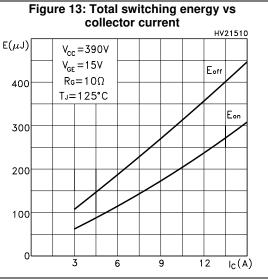


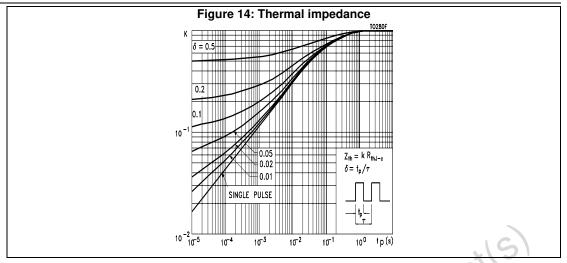


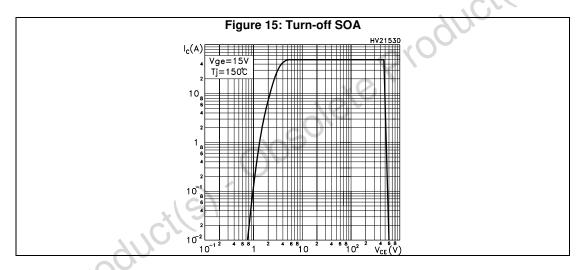


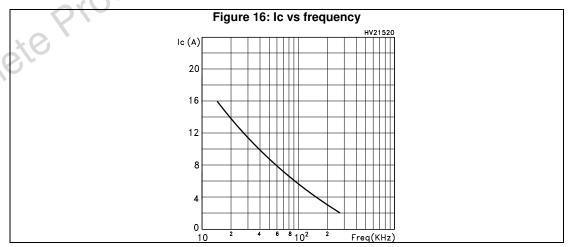






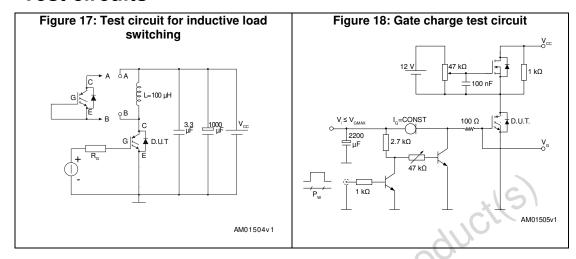


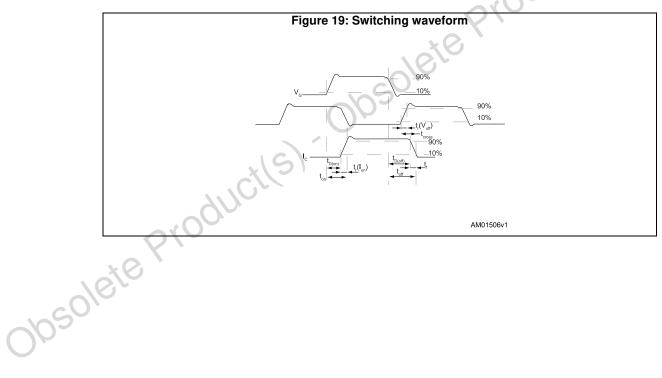




STGP7NC60H Test circuits

3 Test circuits





4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.



STGP7NC60H Package information

4.1 TO-220 type A package information

Figure 20: TO-220 type A package outline

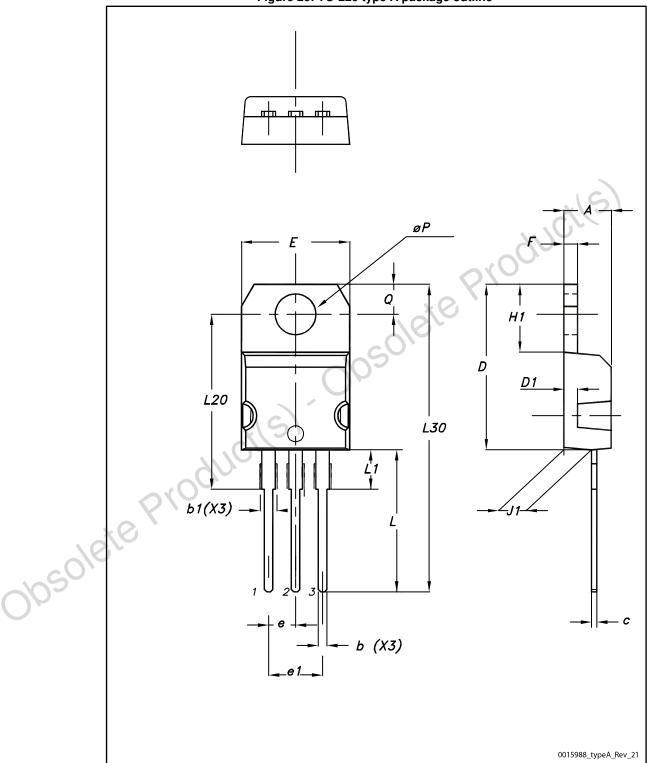


Table 7: TO-220 type A mechanical data

	mm			
Dim.	Min.	Тур.	Max.	
А	4.40		4.60	
b	0.61		0.88	
b1	1.14		1.55	
С	0.48		0.70	
D	15.25		15.75	
D1		1.27		
E	10.00		10.40	
е	2.40		2.70	
e1	4.95		5.15	
F	1.23		1.32	
H1	6.20		6.60	
J1	2.40	,(2.72	
L	13.00	011	14.00	
L1	3.50	40.	3.93	
L20		16.40		
L30		28.90		
øΡ	3.75	9	3.85	
Q	2.65		2.95	
o lete Prod	ucile			

STGP7NC60H Revision history

5 Revision history

Table 8: Document revision history

	Date	Revision	Changes
	20-Aug-2004	1	New datasheet.
	09-Jun-2005	2	Modified title
	04-Jul-2016	3	The part number STGD7NC60HT4 has been moved to a separate datasheet. Modified: title, features and description. Modified: Table 2: "Absolute maximum ratings", Table 3: "Thermal data", Table 4: "Static characteristics", Table 5: "Dynamic characteristics" and Table 6: "IGBT switching characteristics (inductive load)" Updated: Section 5.1: "TO-220 type A package information". Minor text changes.
005019	ate Pro	duci	(S) Obsolete Proc.

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